NSN 5961-01-485-9553

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Semiconductor Device Set - Page 1 of 1



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Inclosure Material:
Plastic all semiconductor device diode
Overall Length:
4.500 inches all semiconductor device diode
End Application:
5895-01-479-9735
Component Function Relationship:
Matched
Component Name And Quantity:
2 semiconductor device diode
Mounting Method:
Terminal all semiconductor device diode
Semiconductor Material:
Silicon all semiconductor device diode
Voltage Rating In Volts Per Characteristic:
124.00 breakdown voltage, dc all semiconductor device diode and 137.00 breakdown voltage, dc all semiconductor device diode and
110.00 working peak reverse voltage all semiconductor device diode
Current Rating Per Characteristic:
5.00 microamperes forward current, average peak all semiconductor device diode
Special Features:
Contains 2ea jantx1n6066a diodes
Terminal Type And Quantity:
2 quick disconnect, female all semiconductor device diode and 1 insulated wire lead w/terminal lug all semiconductor device diode
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
No
Fiig: